

Spin Coherence of Isolated and Exchange-Coupled Donors in Silicon

Alexei M. Tyryshkin¹, Shyam Shankar¹, Shinichi Tojo², John J. L. Morton^{3,4},
Arzhang Ardavan³, Joel W. Ager⁵, Eugene E. Haller^{5,6}, Thomas Schenkel⁵,
Michael L. W. Thewalt⁷, Kohei M. Itoh², and Stephen A. Lyon¹

¹ Dept. of Electrical Engineering, Princeton University

² School of Fundamental Science and Technology, Keio University

³ Dept. of Materials, Oxford University

⁴ CAESR, Clarendon Laboratory, Dept. of Physics, Oxford University

⁵ Lawrence Berkeley National Laboratory

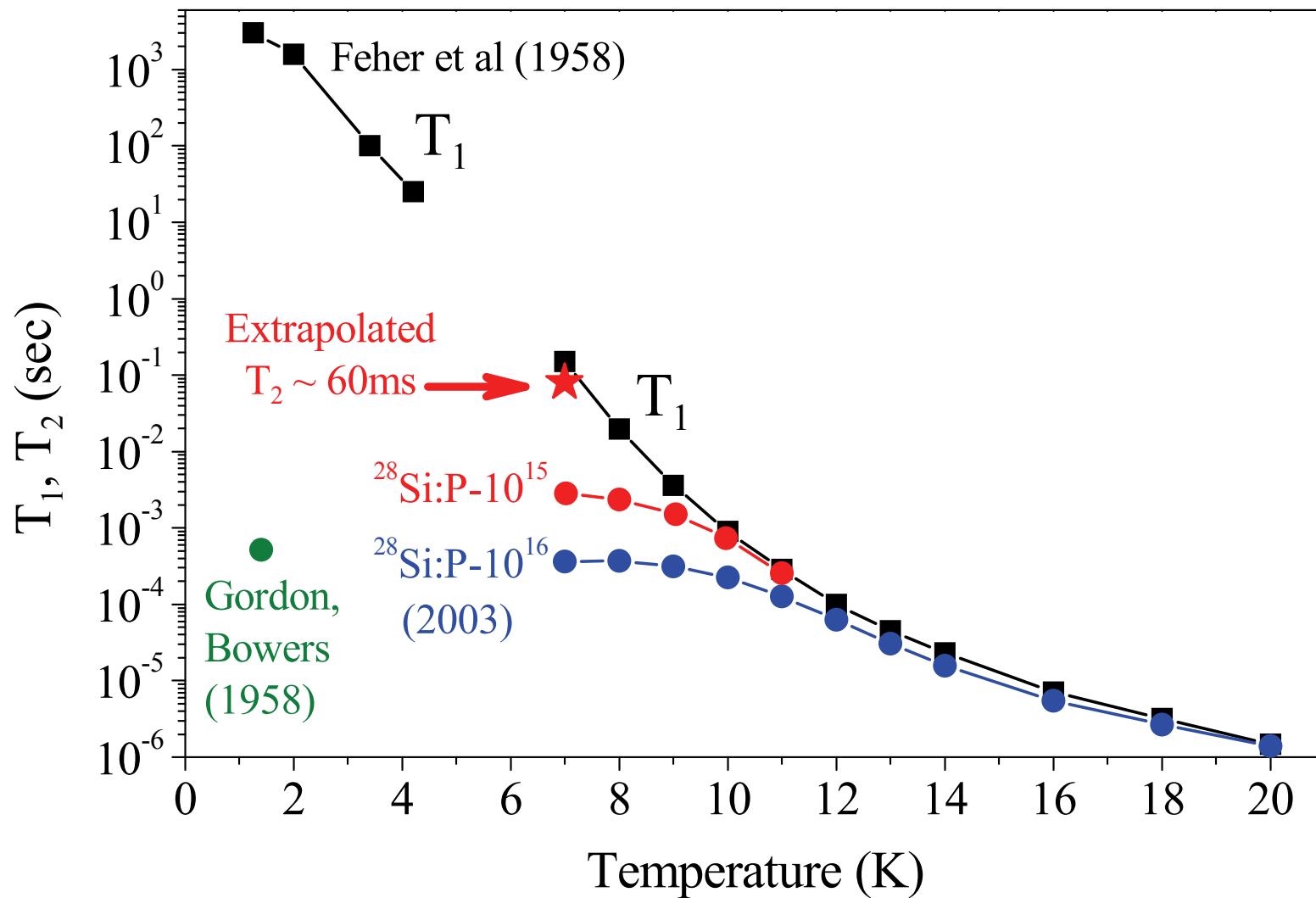
⁶ Materials Science Dept., University of California, Berkeley

⁷ Dept. Physics, Simon Fraser University

Outline:

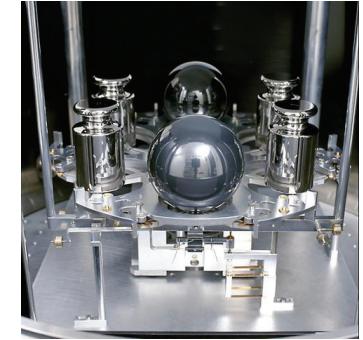
- Isolated donors (very pure ^{28}Si)
 - $T_2 = 0.6 \text{ seconds at } 1.8\text{K}$
- Exchange-coupled donors
 - $T_2 = 1 \text{ microseconds at } 5\text{K}$
- Summary

Donor T_2 in ^{28}Si : History



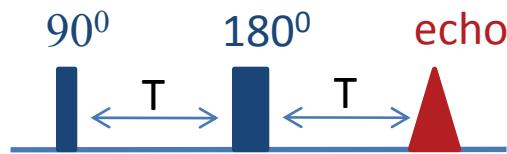
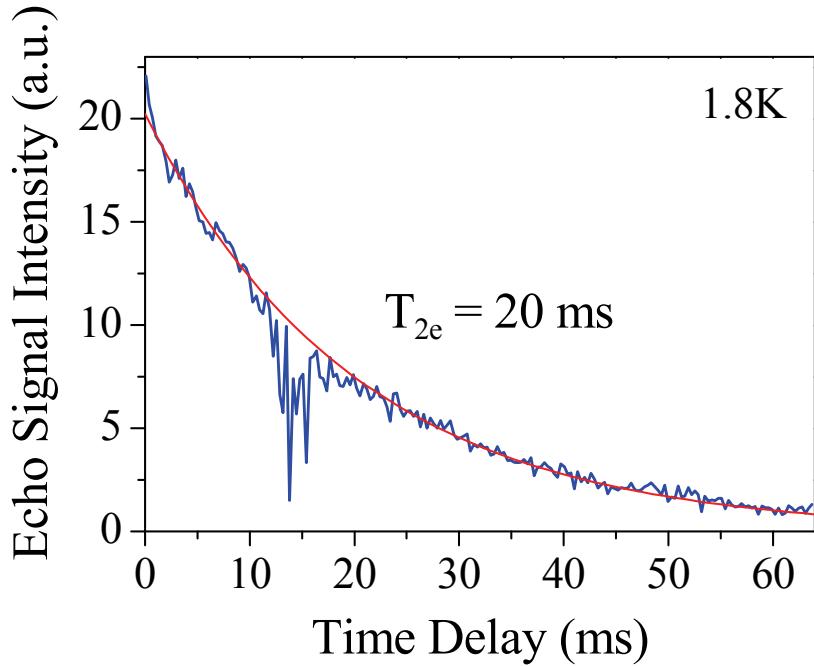
Several Improvements

- **Sample:**
 - Very pure ^{28}Si ($\sim 50\text{ppm } ^{29}\text{Si}$, Avogadro project)
 - Low donor densities ($1\text{e}14 \text{ P/cm}^3$) in a large crystal
 - Slow cooling to LHe temperatures \Rightarrow Less strain
 - Surface passivated with HF
- **Instrumental:**
 - **Magnetic field noise:**
 - Magnitude detection
 - Hall probe wires enclosed in iron tubes
 - **Microphonics noise:**
 - Sand bags to isolate from mechanical noise of the pump
 - BeCu springs for extra support of the resonator
- **LED (1050nm) flash to quickly recover to thermal equilibrium:**
 - Faster measurements at lower temperature

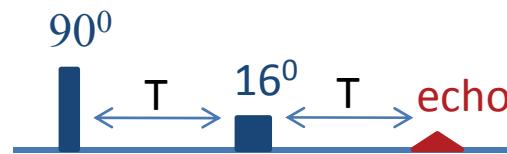
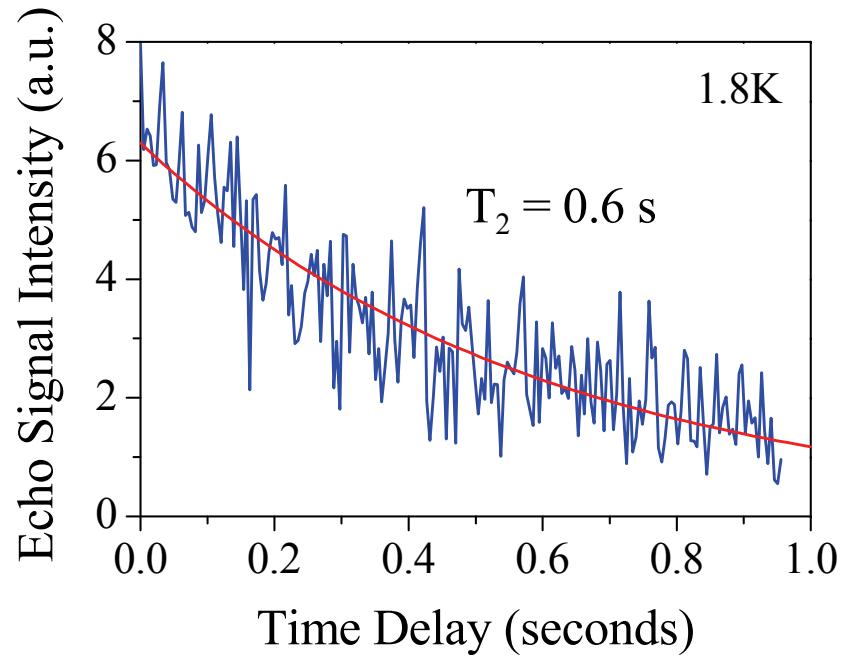


Donor $T_2 = 0.6$ sec at 1.8K

($^{28}\text{Si:P}$, ~50ppm ^{29}Si , $1.2\text{e}14 \text{ P/cm}^3$)

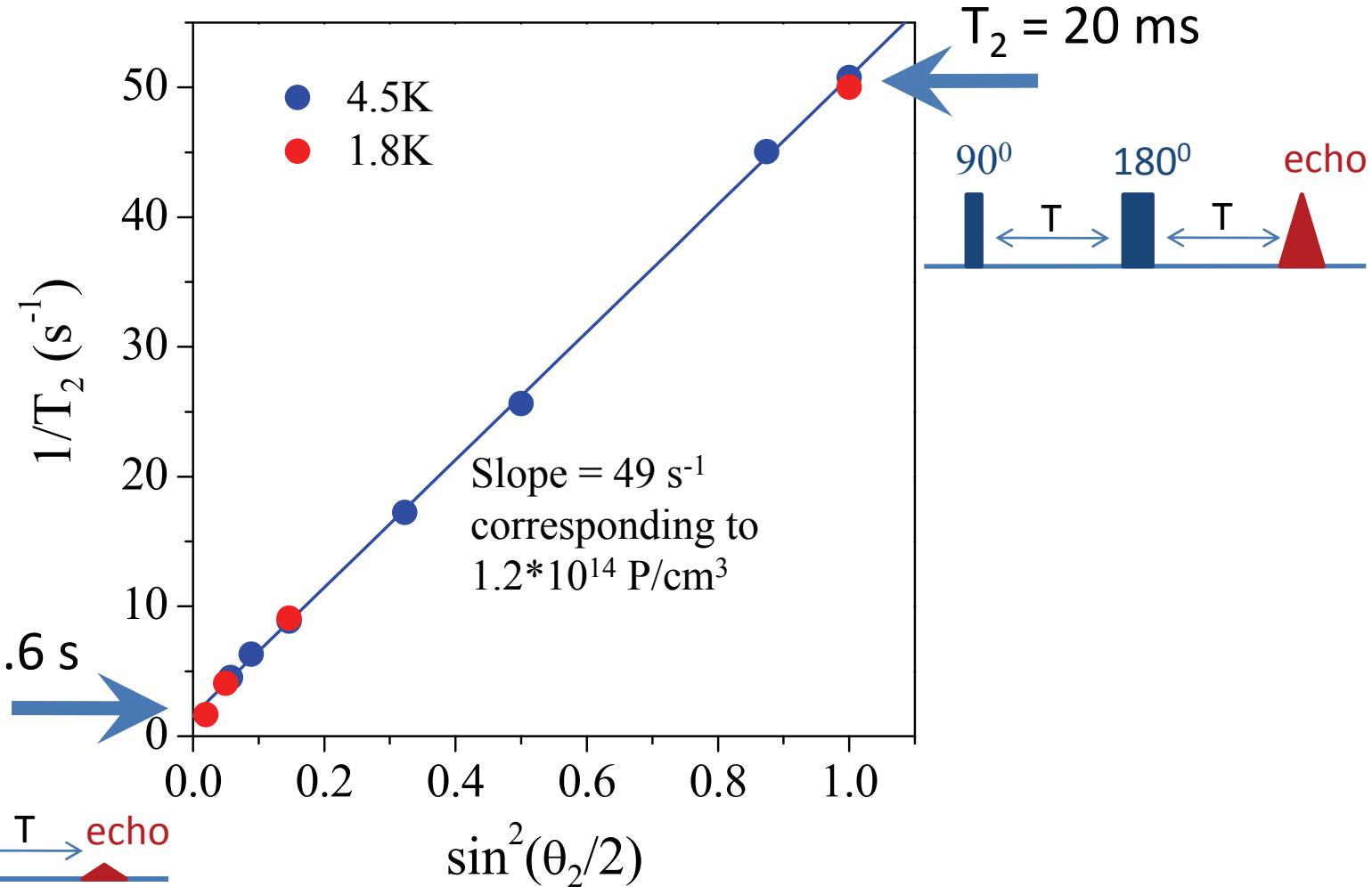


Instantaneous diffusion causes fast T_2

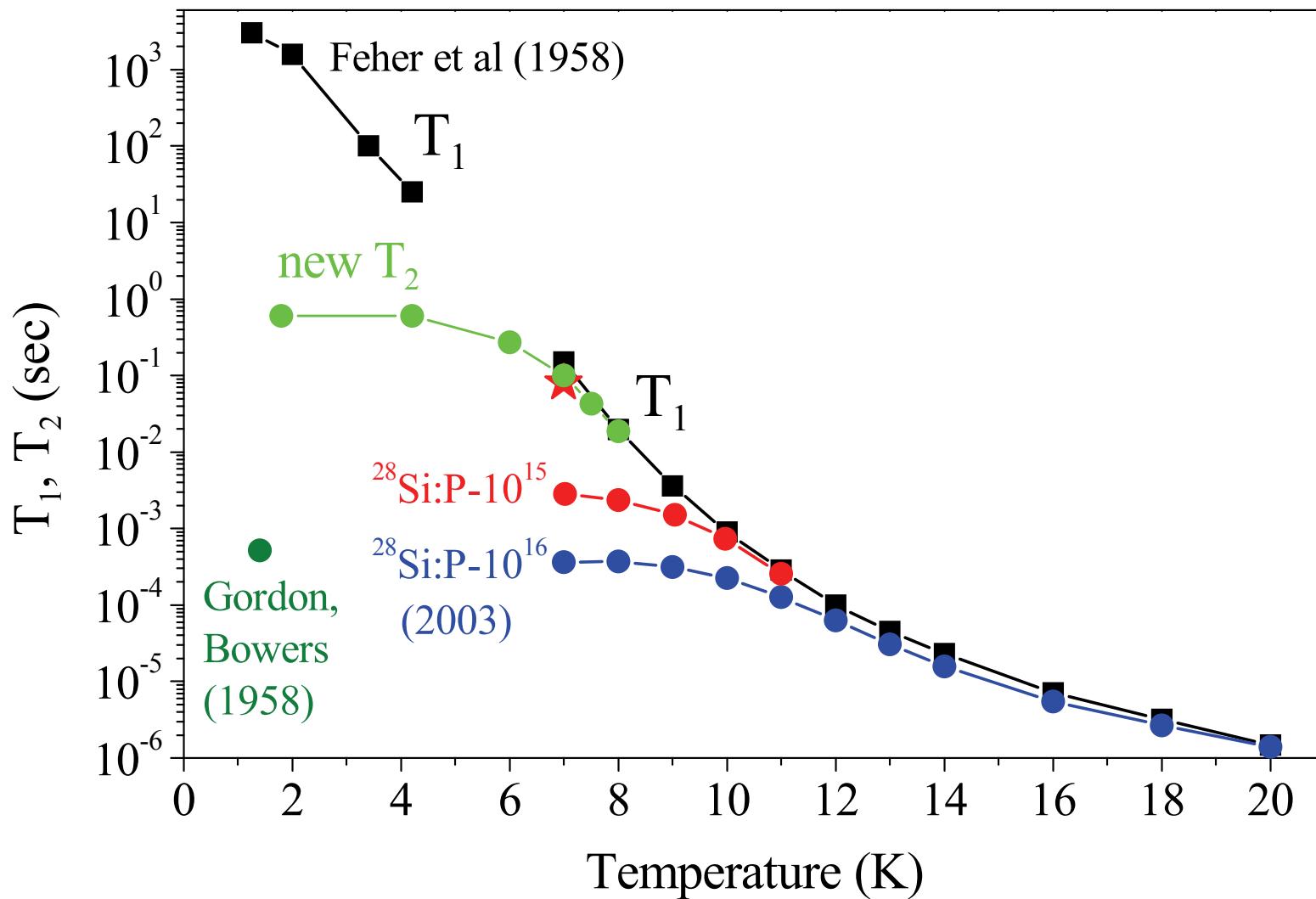


Instantaneous diffusion suppressed!

Instantaneous Diffusion is a Dominant T_2 Mechanism ($^{28}\text{Si:P}$, ~50ppm ^{29}Si , $1.2\text{e}14 \text{ P/cm}^3$)

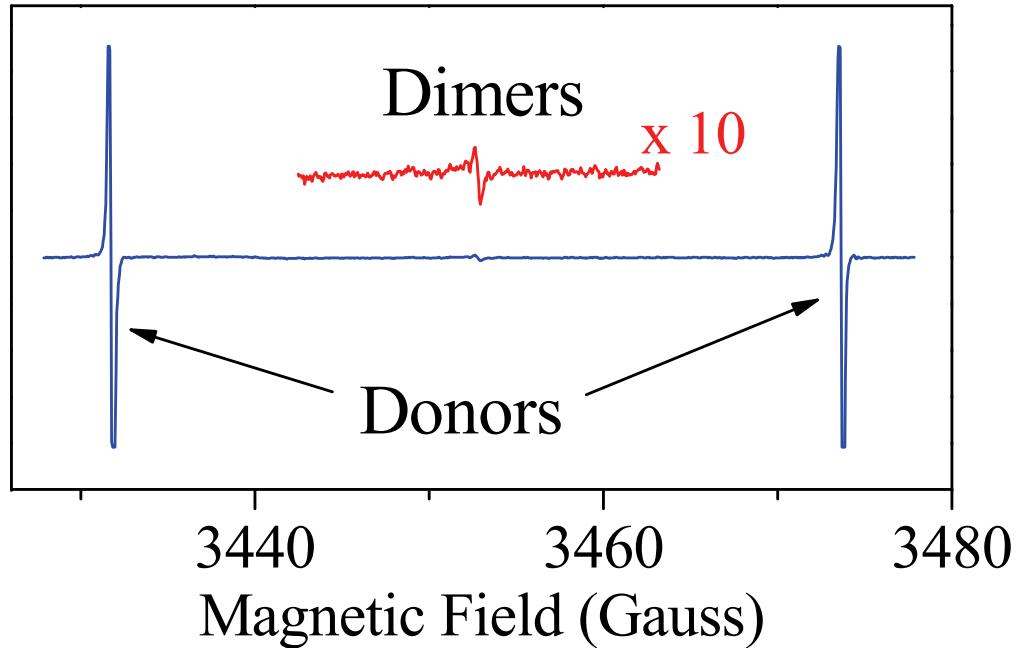


Donor T_2 in ^{28}Si



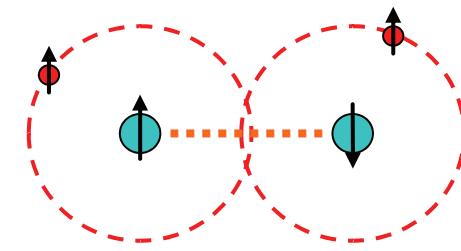
Exchange-Coupled Donors (Dimers)

ESR Intensity

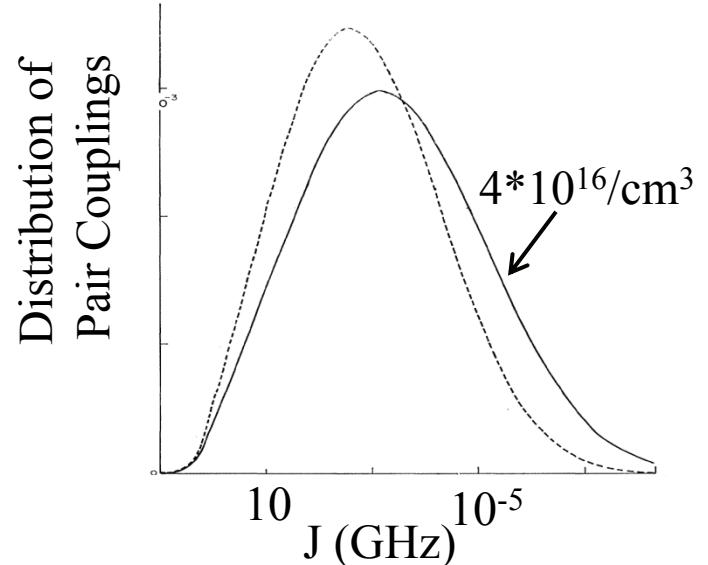


Sample: $^{28}\text{Si:P}$, with $1.6 \times 10^{16} \text{ P/cm}^3$

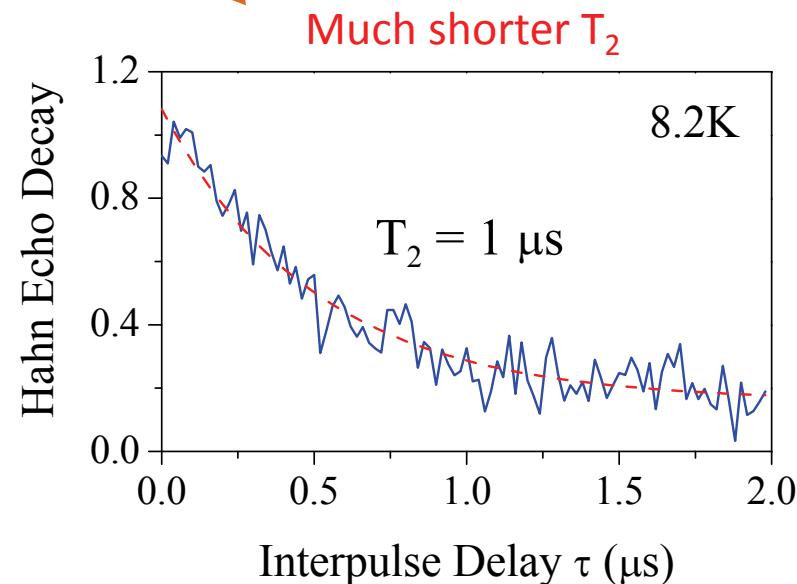
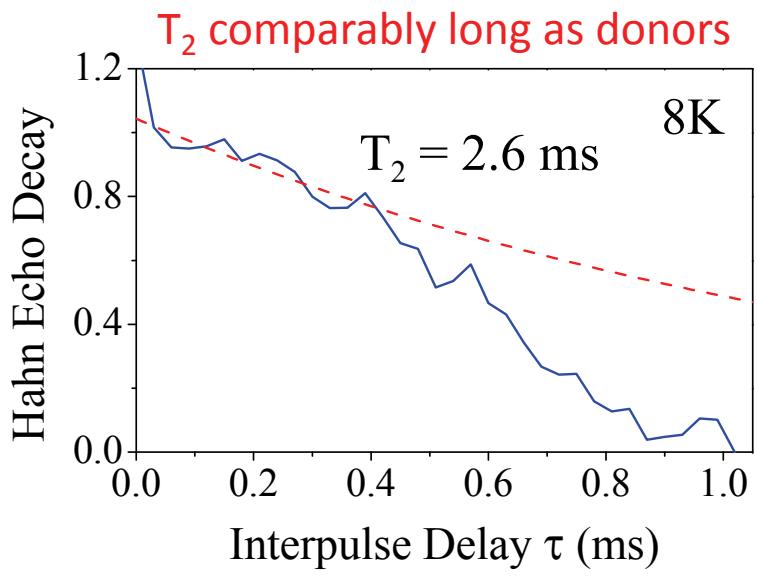
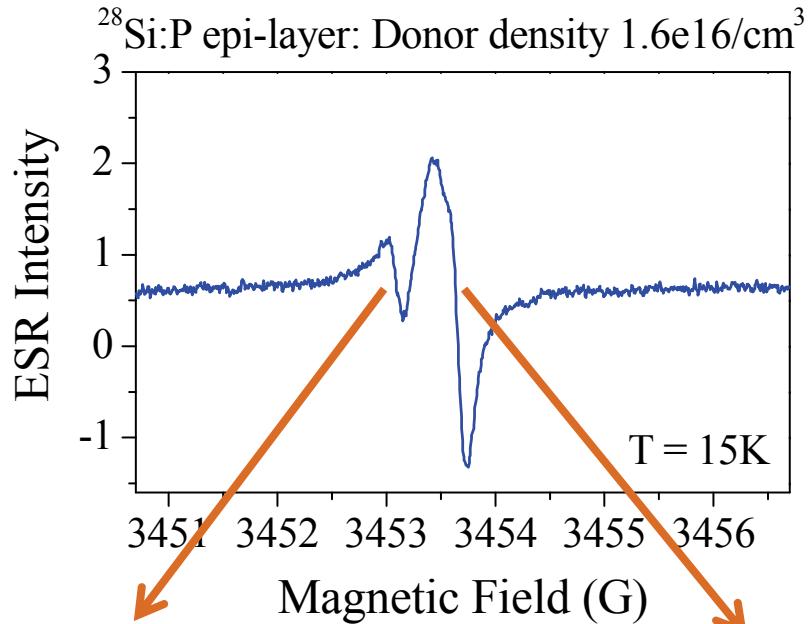
- Random dimers
- Broad distribution of J couplings



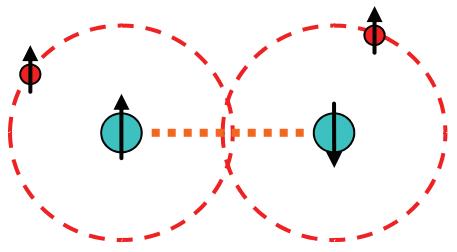
Feher, Fletcher, Gere, PR 100, 1784 (1955)
Cullis, Marko, PRB 1, 632 (1970)
New, Castner, PRB 29, 2077 (1984)



Two Central Lines \Rightarrow Two Distinct T_2

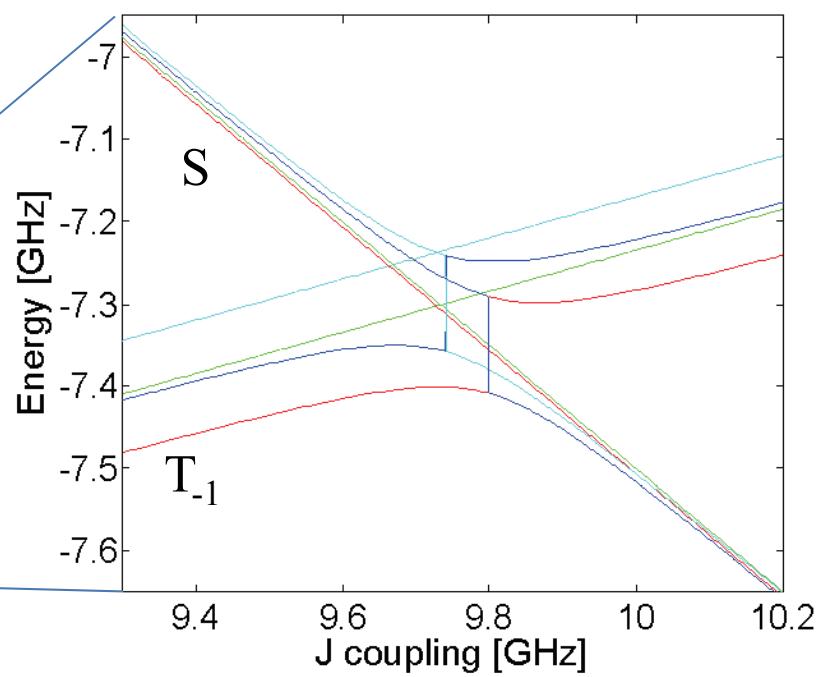
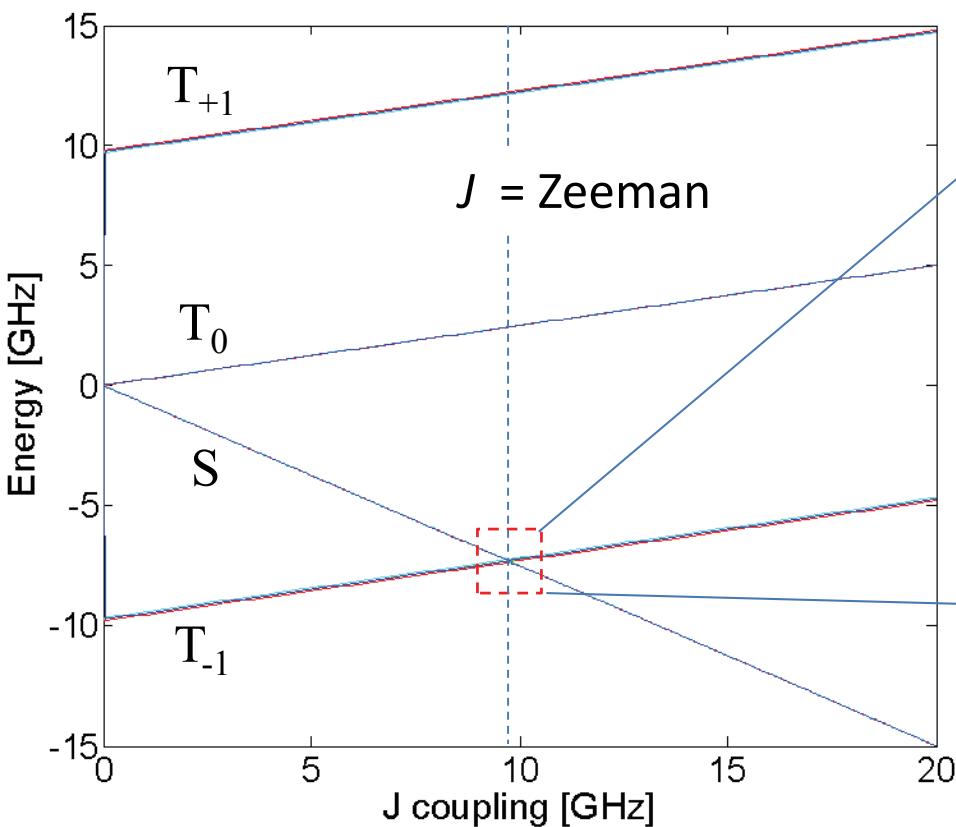


Four Spins \Rightarrow Sixteen States

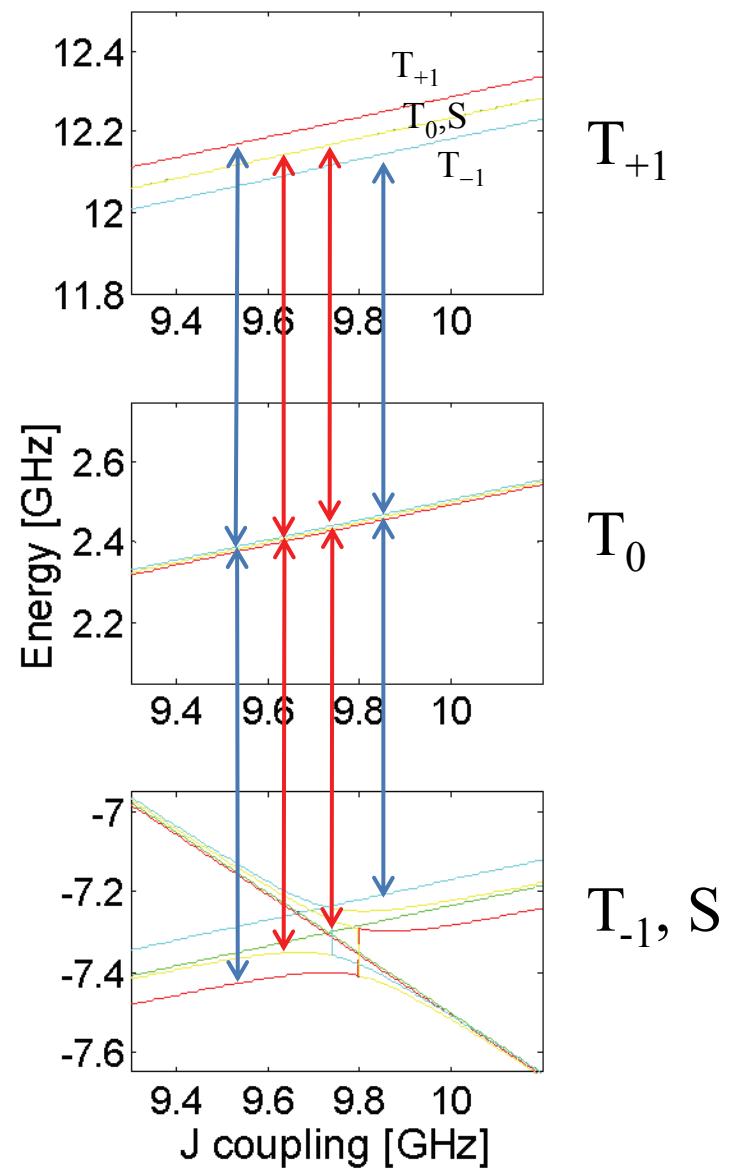
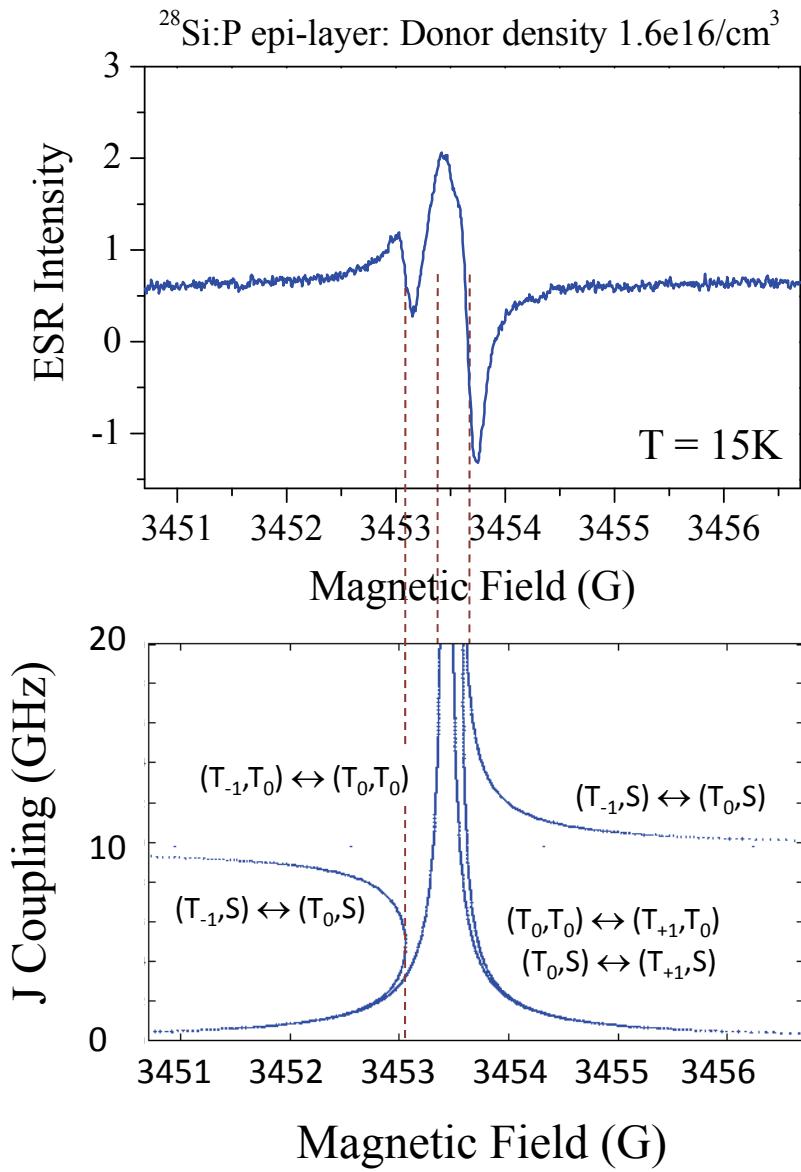


$$H = \omega_e (S_{Z1} + S_{Z2}) + J \cdot \vec{S}_1 \vec{S}_2 + a_P \vec{S}_1 \vec{I}_1 + a_P \vec{S}_2 \vec{I}_2$$

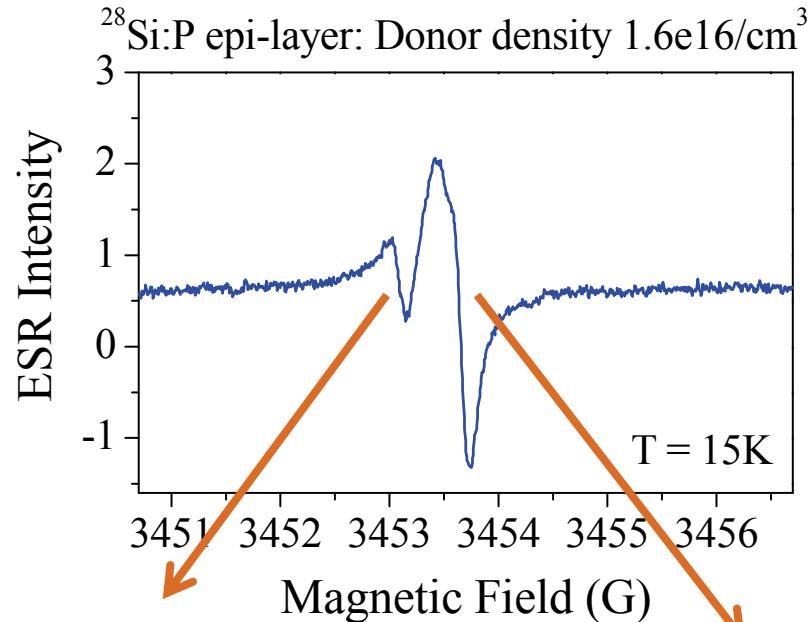
- Zeeman frequency, $\omega_e = 9.7\text{GHz}$
- Exchange coupling, $J = 0 - 100\text{GHz}$
- Hyperfine coupling, $a_p = 117\text{MHz}$



Central Dimer Line: Interpretation



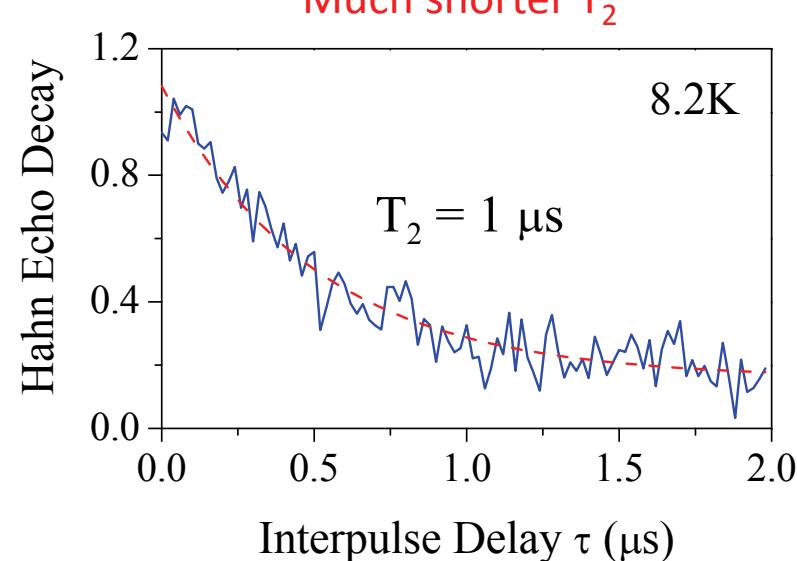
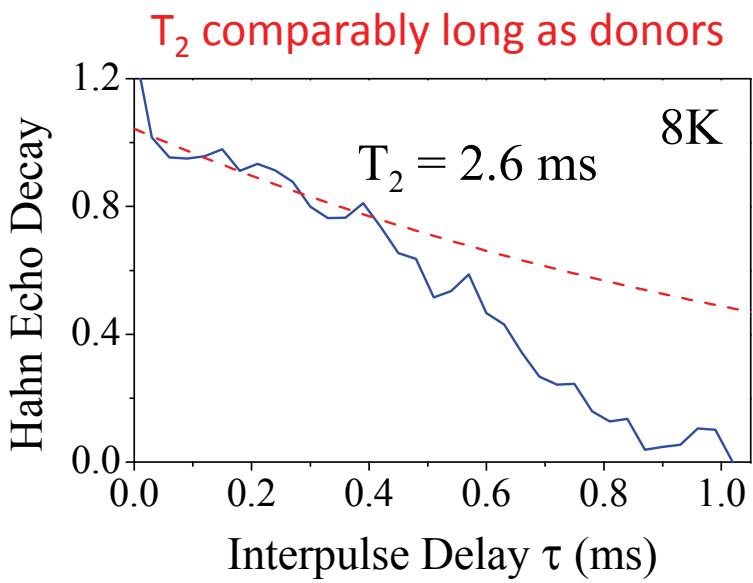
Effect of J-Coupling on T_2



$(T_0,S) \leftrightarrow (T_{+1},S)$ for $J > 4\text{ GHz}$

$(T_{-1},T_0) \leftrightarrow (T_0,T_0)$ for $J > 12\text{ GHz}$

$(T_0,T_0) \leftrightarrow (T_{+1},T_0)$ for $J > 6\text{ GHz}$



Summary

- **Donor $T_2 = 0.6$ seconds in ^{28}Si at 1.8K:**
 - Almost same long as ^{31}P nuclear $T_2 = 2$ seconds!
 - Still much shorter than $T_1 \sim 1000$ seconds at 1.8K
 - There are evidences that T_2 can be further improved! \Rightarrow However, at what cost?
 - Crystal quality
 - Surface passivation
- **Exchange-coupled donors (dimers):**
 - Some transitions, like $(T_0, T_0) \leftrightarrow (T_{+1}, T_0)$, show short $T_2 = 1 \mu\text{s}$
 - Mechanism unknown:
 - Some part of it is a complex coherent evolution in 16x16 Hilbert space. Possibly refocusable?
 - Some part is a real relaxation. E.g. J-coupling fluctuation caused by electric charge noise
 - **Dimers are complicated!**